NSN 5961-01-325-3318

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-325-3318 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.085 inches and 0.125 inches **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak and 180.0 working peak reverse voltage **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute and 2.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No